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Volatility Statement for the SRS CG635

The CG635 contains various types of memories, as listed below:

Non-Volatile Memory:

- | | |
|--------------------|---|
| 60 KB Flash EEPROM | Not user modifiable; contains instrument's firmware |
| 1 KB EEPROM | user modifiable; contains calbytes & instrument settings
<u>To clear:</u>
Depress the backspace key while powering ON the unit. |

Volatile Memory:

- | | |
|-----------|---|
| 2 KB SRAM | user modifiable; used for operation and user settings.
<u>To clear:</u>
Depress the backspace key while powering ON the unit. |
|-----------|---|

Please feel free to contact SRS should you have any further questions.